

Product Change Notice



PCN: PCN_KVR16LE11S8_4I_C2
Date: October 30, 2014

Kingston Technology Company
17600 Newhope Street
Fountain Valley, CA 92708
USA

Product Description: 4GB DDR3L-1600 ECC Unbuffered DIMM CL11 1Rx8 1.35V Intel Certified

Product Affected: KVR16LE11S8/4I

Qualified Build: 9965432-062.A00LF (Hynix A Die) – PHASE OUT
Qualified Build: 9965432-069.A00LF (Kingston F Die) – SHIPPING
Qualified Build: 996xxxx-xxx.A00LF (Hynix B Die) – QUAL IN PROCESS

Type of Change: Build (BOM) Phase Out Notification

Change Description: Build 9965432-062.A00LF using Hynix A Die (H5TC4G83AFR-PBA) on 29nm process is being phased out. Alternate build 9965432-069.A00LF using Kingston F Die available. Replacement Hynix B Die on new 25nm process has been submitted for Intel qualification, estimated for December release.

Phase Out Notice: October 30, 2014

Target End of Life Date: January 5, 2015
